

SK2310AA

N-Channel Enhancement Power Mosfet Specification

Features

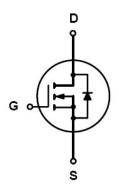
- Advanced trench cell design
- High speed switch

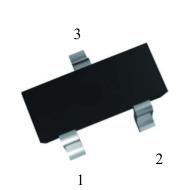
Applications

- Portable appliances
- Notebook/PC appliances
- Power Management
- DC/DC Converter

Quick reference

- BV \geq 60 V ID=3A
- $R_{DS(ON)} \le 90 \text{ m}\Omega$ @ $V_{GS} = 10 \text{ V}$
- Rds(on) $\leq 110 \text{ m}\Omega$ (a) Vgs = 5 V





SOT-23

1: Gate 2: Source 3: Drain

Limiting Values

Symbol	Parameter	Rating	Unit	
V_{DSS}	Drain-Source Voltage	60	\/	
V_{GSS}	Gate-Source Voltage	e Voltage ± 20		

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REV.07



SK2310AA

Electrical Characteristics (Ta = 25°C Unless Otherwise Noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Unit			
Static Characteristics										
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{DS} = 250 \mu\text{A}$		60	-	-	V			
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250 \mu A$		1.0	1.6	2.5	V			
I _{DSS}	Drain Leakage Current	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			-	1	μΑ			
			T _J = 85 °C	-	-	30	μΑ			
I_{GSS}	Gate Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V		·	-	± 100	nΑ			
R _{DS(ON)} ^a	On-State Resistance	$V_{GS} = 10 \text{ V}, I_{DS} = 0.5 \text{A}$		-	-	90	mΩ			
		V _{GS} = 5 V, I _{DS} = 0.5 A		-	<u>-</u> 8	110				
Diode Characteristics ^b										
V _{SD}	Diode Forward Voltage	I _{SD} = 0.5 A, V _{GS} = 0V		-	0.7	1.3	V			

Notes:

This wafer must be stored at N2 box (RH<20 %).

Wafer must be completely assembled within two months.

a: CP measured on wafer by probe card. (RDS(ON) depended on packaged type and amount of bonding wires)

b : Pulse test ; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2\%$

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TK31J60W5,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7 EFC2J004NUZTDG FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7

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